



IXFH26N55Q Information



For Reference Only

Part Number IXFH26N55Q

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 550V 26A TO-247

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXFH26N55Q Specifications

Manufacturer Part Number	IXFH26N55Q
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	HiPerFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	550V
Current - Continuous Drain (Id) @ 25°C	26A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	92nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3000pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	375W (Tc)
Rds On (Max) @ Id, Vgs	230 mOhm @ 13A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AD (IXFH)
Package / Case	TO-247-3
	Report errors?

IXFH26N55Q Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH26N55Q Payment Methods









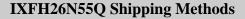
























If you have any question about IXFH26N55Q, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com